

## NCE N-Channel Enhancement Mode Power MOSFET

## **Description**

The NCE82H160 uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. It can be used in a wide variety of applications.

#### **General Features**

•  $V_{DS} = 82V, I_D = 160A$  $R_{DS(ON)} < 4.5 m\Omega @ V_{GS} = 10V$  (Typ:3.8m $\Omega$ )

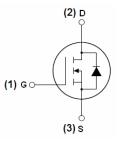
- Special process technology for high ESD capability
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E<sub>AS</sub>
- Excellent package for good heat dissipation

#### **Application**

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



#### Schematic diagram



### Marking and pin assignment



TO-220-3L top view

## **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity	
NCE82H160	NCE82H160	TO-220-3L	-	-	-	

## Absolute Maximum Ratings (T<sub>C</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	82	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	160	Α
Drain Current-Continuous(T <sub>C</sub> =100°C)	I <sub>D</sub> (100℃)	113	Α
Pulsed Drain Current	I <sub>DM</sub>	640	Α
Maximum Power Dissipation	P <sub>D</sub>	285	W
Derating factor		1.9	W/℃
Single pulse avalanche energy (Note 5)	E <sub>AS</sub>	1656	mJ
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 175	$^{\circ}\!\mathbb{C}$



## **Thermal Characteristic**

Thermal Resistance, Junction-to-Case (Note 2)	$R_{ heta Jc}$	0.53	°C/W	
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Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	·					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	82	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =82V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	·					
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250\mu A$	2	3	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	3.8	4.5	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =20A	75	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	101111 011	-	11180	-	PF
Output Capacitance	Coss	$V_{DS}$ =40V, $V_{GS}$ =0V, F=1.0MHz	-	537	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r=1.0WIn2	-	461	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	30	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =40V, $R_L$ =2 $\Omega$	-	48	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{GEN}$ =2.5 $\Omega$	-	82	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	35	-	nS
Total Gate Charge	Qg	\/ -40\/ L -20A	-	201	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =40V,I <sub>D</sub> =20A,	-	47	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> =10V	-	60	-	nC
Drain-Source Diode Characteristics	<u> </u>		•			•
Diode Forward Voltage (Note 3)	$V_{SD}$	V <sub>GS</sub> =0V,I <sub>S</sub> =160A	-	-	1.2	V
Diode Forward Current (Note 2)	Is	-	-	-	160	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF = 20A	-	70	-	nS
Reverse Recovery Charge	Qrr	$di/dt = 100A/\mu s^{(Note3)}$	-	140	-	nC

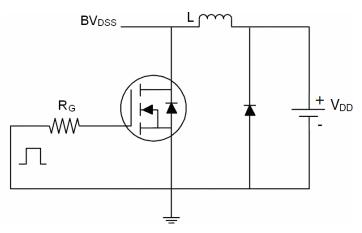
#### Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition: Tj=25 $^{\circ}$ C,VDD=40V,VG=10V,L=0.5mH,Rg=25 $\Omega$

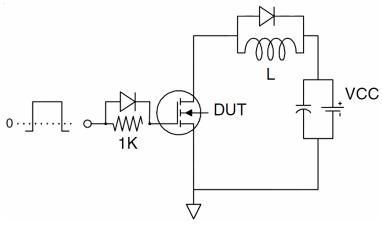


## **Test circuit**

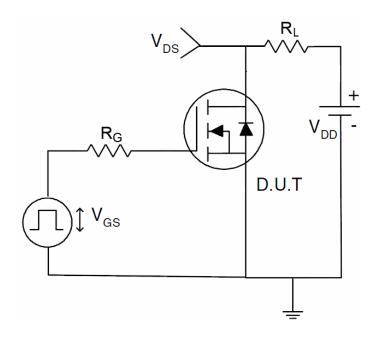
# 1) E<sub>AS</sub> test Circuit



# 2) Gate charge test Circuit

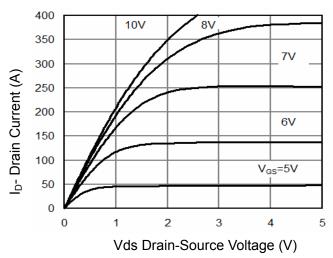


### 3) Switch Time Test Circuit

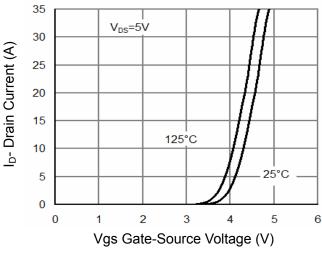




## Typical Electrical and Thermal Characteristics (Curves)



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

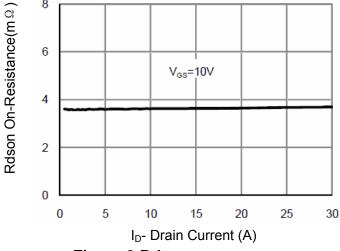


Figure 3 Rdson- Drain Current

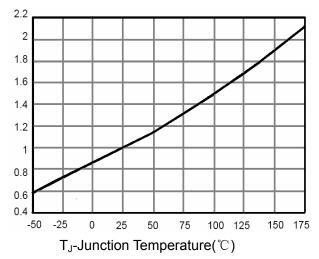


Figure 4 Rdson-JunctionTemperature

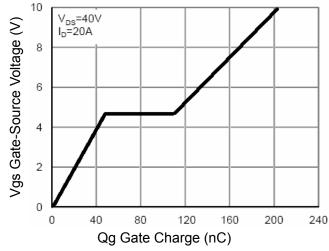


Figure 5 Gate Charge

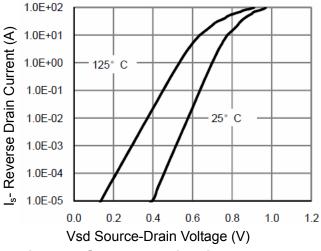
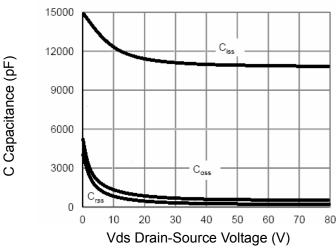


Figure 6 Source- Drain Diode Forward





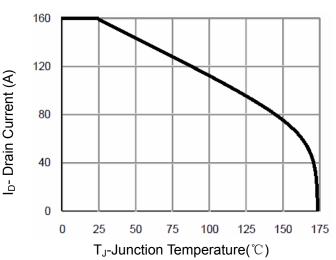
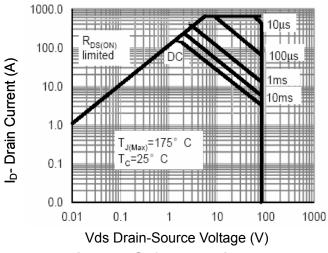
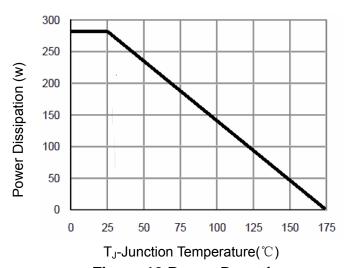


Figure 7 Capacitance vs Vds

**Figure 9 Current De-rating** 





**Figure 8 Safe Operation Area** 

Figure 10 Power De-rating

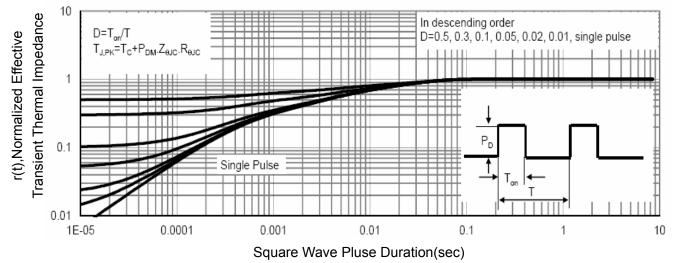
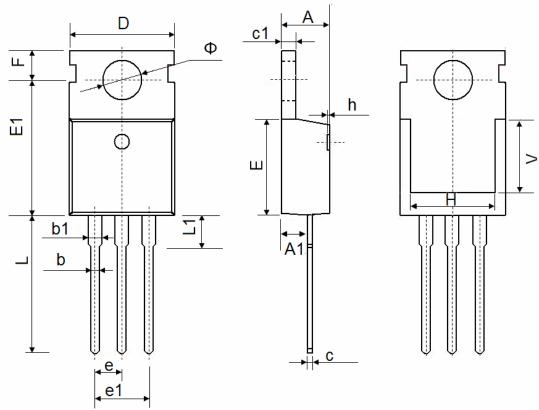


Figure 11 Normalized Maximum Transient Thermal Impedance



# **TO-220-3L Package Information**



Ob. a.l.	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min.	Max.	Min.	Max.		
A	4.400	4.600	0.173	0.181		
A1	2.250	2.550	0.089	0.100		
b	0.710	0.910	0.028	0.036		
b1	1.170	1.370	0.046	0.054		
С	0.330	0.650	0.013	0.026		
c1	1.200	1.400	0.047	0.055		
D	9.910	10.250	0.390	0.404		
E	8.9500	9.750	0.352	0.384		
E1	12.650	12.950	0.498	0.510		
е	2.540	TYP.	0.100	0.100 TYP.		
e1	4.980	5.180	0.196	0.204		
F	2.650	2.950	0.104	0.116		
Н	7.900	8.100	0.311	0.319		
h	0.000	0.300	0.000	0.012		
L	12.900	13.400	0.508	0.528		
L1	2.850	3.250	0.112	0.128		
V	7.500	7.500 REF.		REF.		
Ф	3.400	3.800	0.134	0.150		

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